

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.



April 2015

FGH40N65UFD_F085 650 V, 40 A Field Stop IGBT

FGH40N65UFD_F085 650 V, 40 A Field Stop IGBT

Features

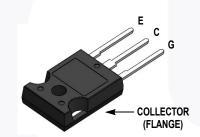
- · High Current Capability
- Low Saturation Voltage: $V_{CE(sat)}$ = 1.8 V @ I_C = 40 A
- · High Input Impedance
- · Fast Switching
- RoHS Compliant
- · Qualified to Automotive Requirements of AEC-Q101

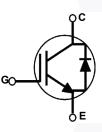
Applications

- · Automotive Chargers, Converters, High Voltage Auxiliaries
- Inverters, PFC, UPS

General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for Automotive Chargers, Inverter, and other applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		650	V
V _{GES}	Gate to Emitter Voltage		± 20	V
I _C	Collector Current	@ T _C = 25°C	80	A
	Collector Current	@ T _C = 100°C	40	A
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25 ^o C	120	А
P _D	Maximum Power Dissipation	@ T _C = 25°C	290	W
	Maximum Power Dissipation	@ T _C = 100°C	116	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes: 1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур	Unit	
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	0.43	°C/W	
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	1.45	°C/W	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	40	°C/W	

G
Т
4
Ò
Ζ
ົດ
G
C
Т
١Ť
ĒΠ.
0
8
G
9
S
Õ
<
-
4
40
40 A
0 P
0 A
0 A Fie
0 A Fiel
0 A Field
0 A Fiel
0 A Field S
0 A Field S
0 A Field Stop
0 A Field Stop
0 A Field Stop I
0 A Field Stop IG

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH40N65UFDTU_F085	FGH40N65UFD	TO-247	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 250 μA	650	-	-	V
ΔΒV _{CES} ΔΤ _J	Temperature Coefficient of Breakdown Voltage	V_{GE} = 0 V, I _C = 250 μ A	-	0.6	-	V/ºC
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA
I _{GES}	G-E Leakage Current	V_{GE} = V_{GES} , V_{CE} = 0 V	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 250 μA, V _{CE} = V _{GE}	4.0	5.2	6.5	V
		$I_{\rm C}$ = 40 A, $V_{\rm GE}$ = 15 V	-	1.8	2.4	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$	-	2.0	-	V
Dynamic C	Characteristics				1	
C _{ies}	Input Capacitance		-	1860	-	pF
C _{oes}	Output Capacitance	$V_{CE} = 30 V, V_{GE} = 0 V,$	-	200	-	pF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz	-	65	-	pF
	Characteristics		-	23	-	ns
t _{d(on)} t _r	Rise Time	-	-	35	-	ns
t _{d(off)}	Turn-Off Delay Time	1 = 100 V = 100 A	-	126	-	ns
t _f	Fall Time	$V_{CC} = 400 \text{ V}, \text{ I}_{C} = 40 \text{ A},$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ Inductive Load, $T_{C} = 25^{\circ}\text{C}$	-	26	60	ns
E _{on}	Turn-On Switching Loss		-	1.28	- /	mJ
E _{off}	Turn-Off Switching Loss	-	-	0.50	-	mJ
E _{ts}	Total Switching Loss			1.78		mJ
t _{d(on)}	Turn-On Delay Time		-	21	-	ns
t _r	Rise Time	-	-	39	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 40 A,	-	131	-	ns
t _f	Fall Time	R _G = 10 Ω, V _{GE} = 15 V,	-	72	-	ns
Eon	Turn-On Switching Loss	Inductive Load, $T_C = 125^{\circ}C$	-	1.62	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.79	-	mJ
	Total Switching Loss		-	2.41	-	mJ
Ets			-	119	-	nC
	Total Gate Charge		_	110		
E _{ts} Q _g Q _{ge}	Total Gate Charge Gate to Emitter Charge	V _{CE} = 400 V, I _C = 40 A, V _{GE} = 15 V	-	14	-	nC

Symbol	Parameter	Test Condition	ns	Min.	Тур.	Max	Unit
V _{FM} Diode Forward Voltage	I _F = 20 A	T _C = 25°C	-	1.80	2.6	v	
	blode i olivara voltage	1F 207	T _C = 125 ^o C	-	1.71	-	
t	Diode Reverse Recovery Time	I _F =20 A, di _F /dt = 200 A/μs	T _C = 25 ^o C	-	65	-	ns
۲r			T _C = 125°C	-	215	-	
Q _{rr}	Diode Reverse Recovery Charge	$r_{\rm F} = 20$ Å, $a_{\rm F} a_{\rm C} = 200$ Å/µ3	T _C = 25 ^o C	-	145	-	nC
α _f r			T _C = 125 ^o C	-	775	-	

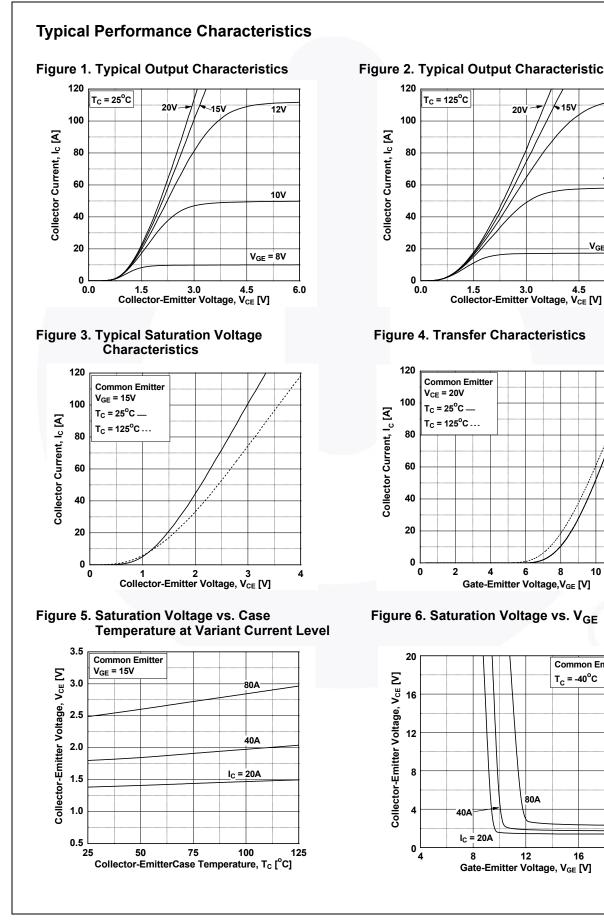


Figure 2. Typical Output Characteristics

20

6

80A

12

8

10

Common Emitter

 $T_c = -40^{\circ}C$

16

12

15V

12V

10V

V_{GE} = 8V

6.0

20

Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

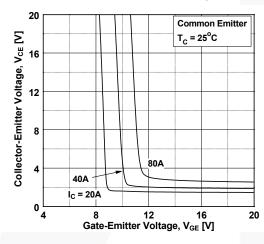


Figure 9. Capacitance Characteristics

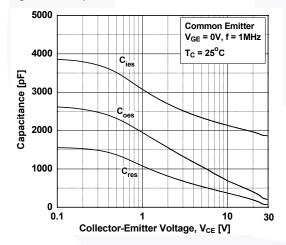


Figure 11. SOA Characteristics

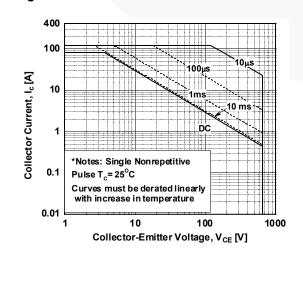
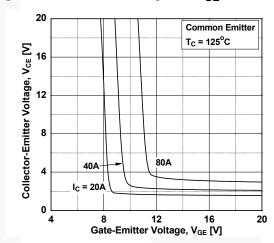
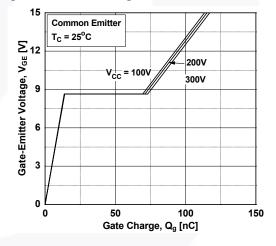


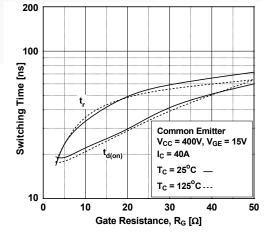
Figure 8. Saturation Voltage vs. VGE











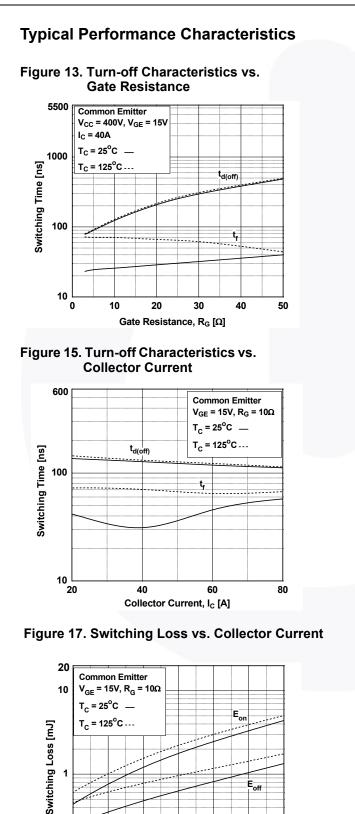
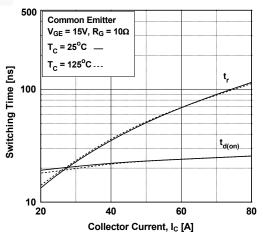
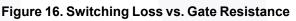
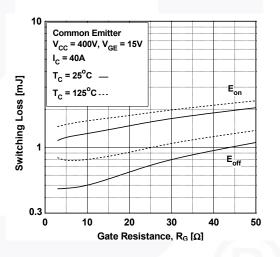
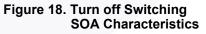


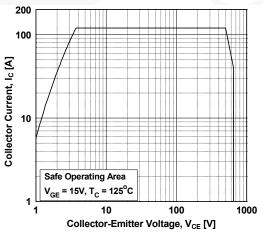
Figure 14. Turn-on Characteristics vs. **Collector Current**











0.1

20

30

40

50

Collector Current, Ic [A]

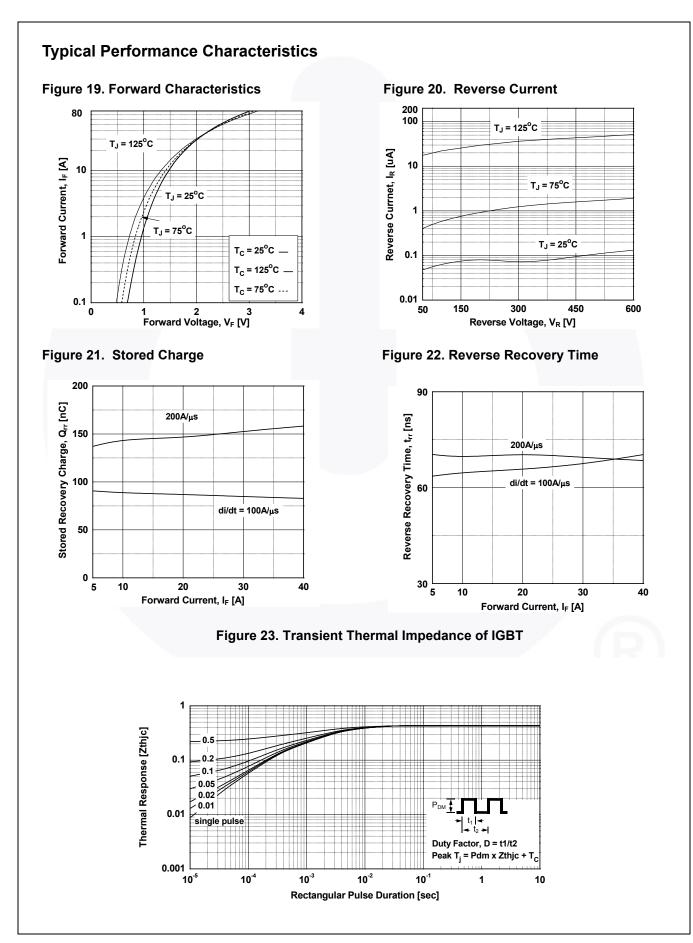
60

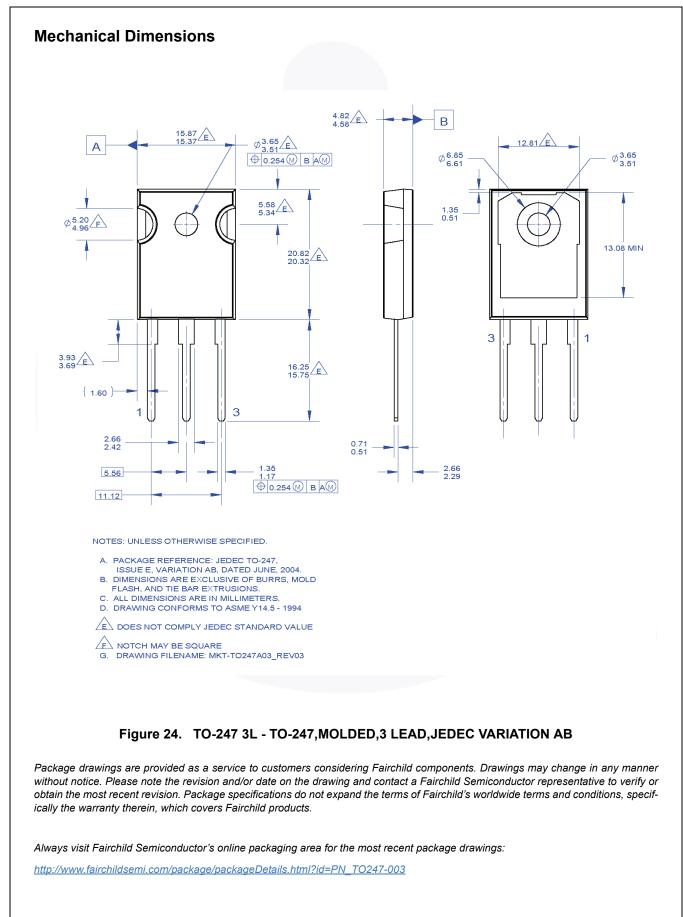
E_{off}

70

80









TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower AttitudeEngine TMF-PFS TMAttitudeEngine Awind2 $^{\odot}$ Awind2 $^{\odot}$ Awind2 $^{\odot}$ BitSiC TMGlobal Power Resource SM Green FPS TM Green FPS TO TM Green FPS TO TO TO CroPOWER TM CorePOWER TO CroPOWER TO TO CROSSVOLT TM Current Transfer Logic TM Dual ColTM Dual ColTM Dual ColTM Dual ColTM Dual ColTM Dual ColTM Dual ColTM Edse TM Edse TM MicroPak TM MicroPak TM MicroPak TM MicroPak TM MicroPak TM MilerDrive TM MilerDrive TM Fairchild Semiconductor Section FACT Quiet Series TM FACT Section FACT Quiet Series TM FACT Section FACT Quiet Series TM FACT Section FACT Quiet Series TM FACT Section FACT Quiet Series TM FACT Section FACT Section TM FACT Section SatucOre TM FACT Section SatucOre TM FACT Section SatucOre TM FACT Section SatucOre SatucO	OPTOPLANAR [®] Dower Supply WebDesigner [™] PowerTrench [®] PowerXS [™] Programmable Active Droop [™] QFET [®] QS [™] Quiet Series [™] der RapidConfigure [™] Saving our world, 1mW/W/kW at a time [™] SignalWise [™] SmartMax [™] SMART START [™] Solutions for Your Success [™] SPM [®] STEALTH [™] SuperSOT [™] -3 SuperSOT [™] -6 SuperSOT [™] -6 SuperSOT [™] -8 SupreMOS [®] SyncFET [™] Sync-Lock [™]	EGENERAL TinyBoost [®] TinyBoost [®] TinyCalc™ TinyLogic [®] TINYOPTO™ TinyPOWer™ TinyPWM™ TinyWire™ TranSiC™ TriFault Detect™ TRUECURRENT®+ µSerDes™ UHCa FRFET™ UhiFET™ VisualMax™ VoltagePlus™ XSens™ 仙童 ™
--	---	---

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Product Status	Definition
Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
	Formative / In Design First Production Full Production

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC